

Silicon TVS diodes

 ESD / transient protection of automotive CAN / LIN bus networks / transceivers, industrial bus systems and power supply lines according to:

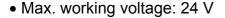
IEC61000-4-2 (ESD): ± 30 kV (air / contact)

IEC61000-4-4 (EFT): 80 A (5/50 ns)

IEC61000-4-5 (surge): 5 A (8/20 μs)

ISO7637-2: Pulse 1 (max. 50 V),

Pulse 2 (max. 125 V), Pulse 3a, b (max. 800 V)



Low capacitance: 24 pF typ.

Low clamping voltage: < 41 V

• Extremely low reverse current: < 1 nA typ.

• Pb-free (RoHS compliant) package

• Qualified according AEC Q101

Applications

- Low and High-Speed CAN
- Fault Tolerant CAN
- Industrial control networks
- 12/24 V DC power supply lines





ESD24VS2U



| Туре | Package | Configuration | Marking |
|-----------|---------|---------------------------|---------|
| ESD24VS2U | SOT23 | 2 lines, uni-directional* | EUs |

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^{* 1} line, bi-directional between pins 1 and 2, if pin 3 is not connected



Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

| Parameter | Symbol | Value | Unit |
|--|------------------|--------|------|
| ESD contact discharge ¹⁾ | V _{ESD} | 30 | kV |
| Peak pulse current ($t_p = 8 / 20 \mu s)^2$) | I _{pp} | 5 | А |
| Peak pulse power ($t_p = 8 / 20 \mu s)^2$) | P_{pk} | 230 | W |
| Operating temperature range | T_{op} | -55150 | °C |
| Storage temperature | $T_{\rm stg}$ | -65150 | |

Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|-------------------|--------|------|------|------|
| | | min. | typ. | max. | |
| Characteristics - | | | | | |
| Reverse working voltage | V_{RWM} | - | - | 24 | V |
| Breakdown voltage | $V_{(BR)}$ | 26 | - | 32 | |
| $I_{(BR)} = 1 \text{ mA}$ | | | | | |
| Reverse current | I _R | - | <1 | 10 | nA |
| V _R = 24 V | | | | | |
| Clamping voltage | V_{CL} | | | | V |
| $I_{PP} = 1 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2}$ | | - | 30 | 34 | |
| $I_{PP} = 5 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2}$ | | - | 36 | 41 | |
| Line capacitance ³⁾ | C _T | | | | pF |
| V_{R} = 0 V, f = 1 MHz, ESD24VS2U , | | | | | |
| (pins 1 to 2, pin 3 n.c.) | | _ | 24 | 28 | |
| V_{R} = 0 V, f = 1 MHz, ESD24VS2U, | | | | | |
| (pins 1 or 2 to 3) | | - | 48 | 52 | |

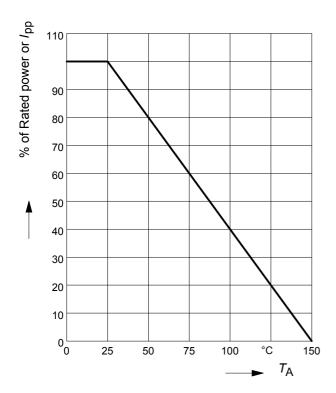
 $^{^{1}}V_{\mbox{\footnotesize{ESD}}}$ according to IEC61000-4-2. Device stressed with 10 positive / negative ESD pulses.

 $^{^2\}emph{I}_{\mbox{\footnotesize{pp}}}$ according to IEC61000-4-5. Non-repetitive current pulse.

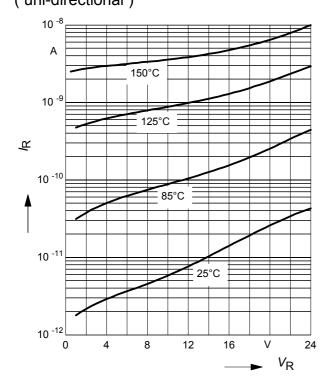
³Total capacitance to ground (per linie)



Power derating curve $P_{pk} = f(T_A)$

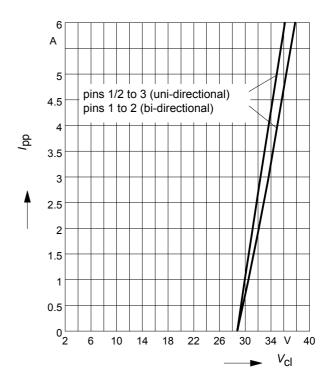


Reverse current $I_R = f(V_R)$ $T_A = Parameter$, pins 1 / 2 to 3 (uni-directional)



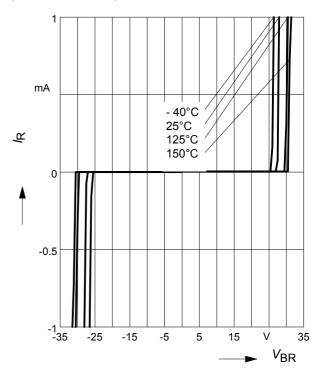
Clamping voltage, $V_{cl} = f(I_{pp})$

$$t_{\rm p}$$
 = 8 / 20 $\mu {\rm s}$



Breakdown voltage $V_{BR} = f(I_R)$

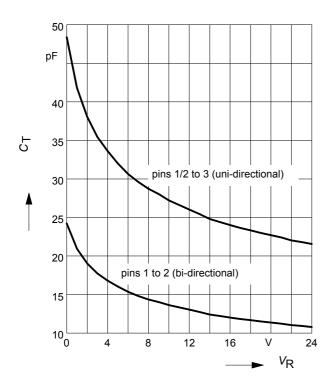
 T_A = Parameter, pins 1 to 2 (bi-directional)





Line capacitance $C_T = f(V_R)$

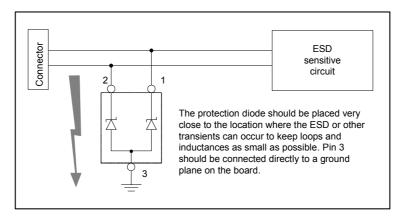
f = 1MHz





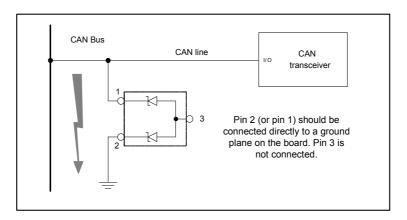
Application example ESD24VS2U (uni-directional)

12V / 24V DC power supply line protection



Application example ESD24VS2U (bi-directional)

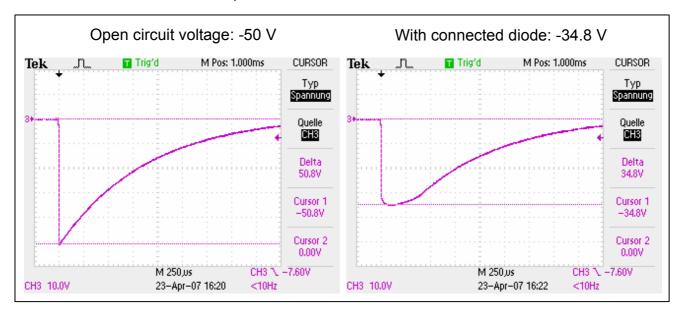
Single Wire CAN and LIN bus protection





Clamping voltage according to ISO 7637-2: Pulse 1

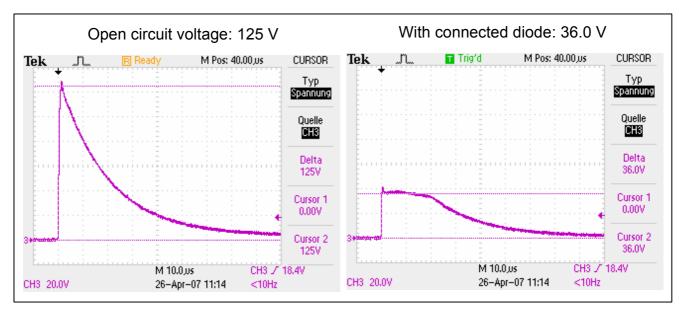
Ri = 10 Ohm, td = 2 ms, 5000 pulses





Clamping voltage according to ISO 7637-2: Pulse 2a

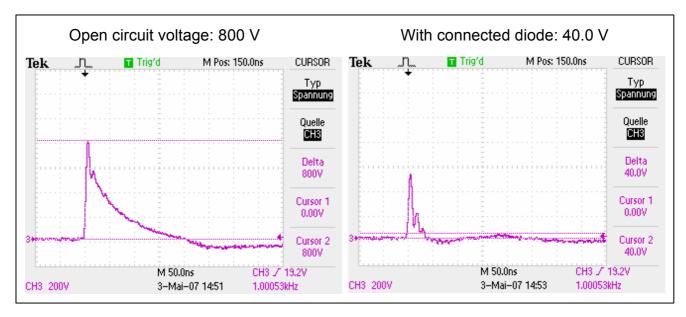
Ri = 10 Ohm, td = 2 us, 4000 pulses, 60 min





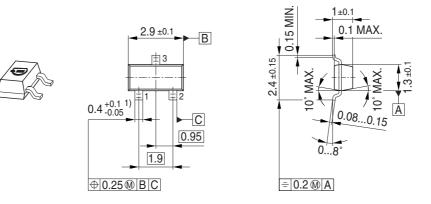
Clamping voltage according to ISO 7637-2: Pulse 3

Ri = 50 Ohm, td = 100 ns, 10 min

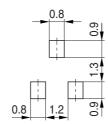




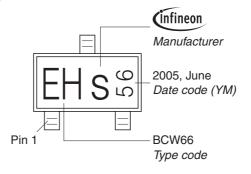
Package Outline



1) Lead width can be 0.6 max. in dambar area Foot Print

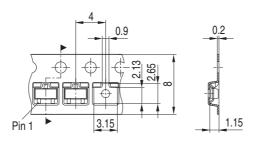


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



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